



Electronic Circuits – Assignment 02

Diode Applications I

#	Student ID	Student Name	Grade (10)
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Delivery Date	
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١. يتم تسليم التمرين محلولا في خلال أسبوع من تاريخ التمرين، و يتم حذف درجتين من التمرين عن كل أسبوع تأخير

٢. يتم التسليم لمعيد المقرر مباشرة

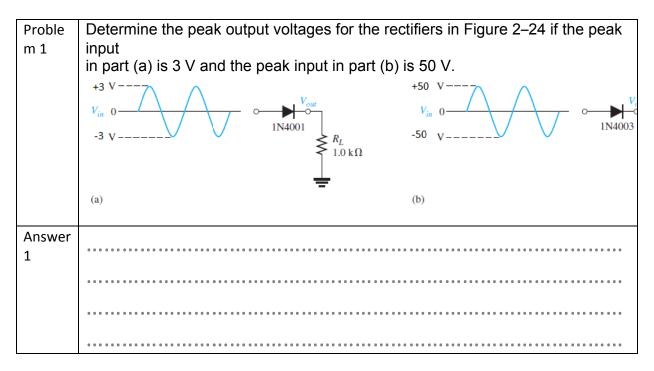
٣. تتم أجابه التمرين في نفس ورق الأسئلة

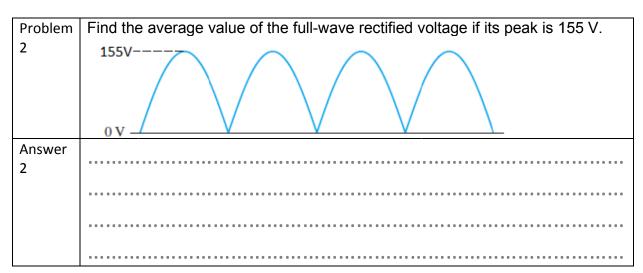




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Problems 1









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T & False questions

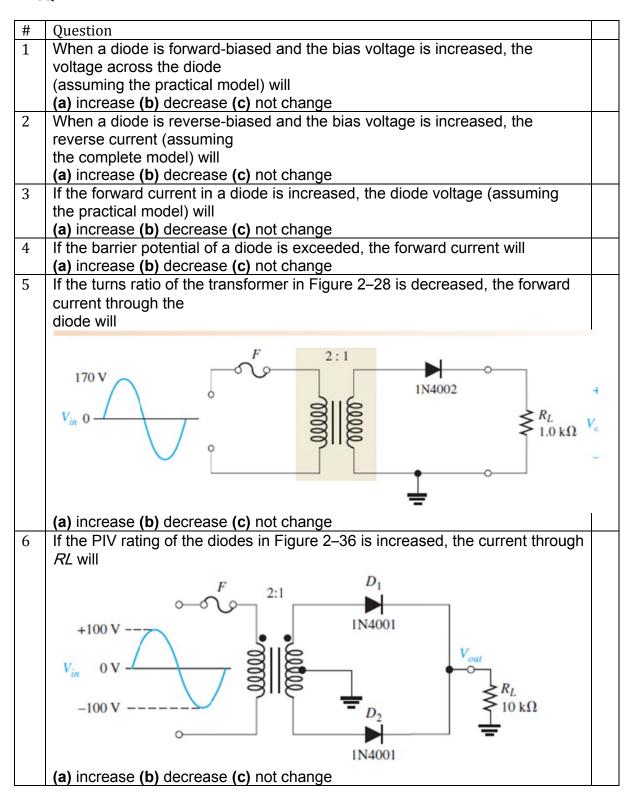
#	Question	Answer
1	The two regions of a diode are the anode and the collector.	
2	A diode conducts current when forward-biased.	
3	Two types of current in a diode are electron and hole.	
4	The output frequency of a half-wave rectifier is twice the input	
	frequency.	
5	PIV stands for positive inverse voltage.	
6	The output frequency of a full-wave rectifier is twice the input frequency.	



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MCQ 1







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#	Question	
1	To forward-bias a diode,	
	(a) an external voltage is applied that is positive at the anode and	
	negative at the cathode	
	(b) an external voltage is applied that is negative at the anode and	
	positive at the cathode	
	(c) an external voltage is applied that is positive at the p region and	
	negative at the <i>n</i> region	
	(d) answers (a) and (c)	
2	Although current is blocked in reverse bias,	
	(a) there is some current due to majority carriers	
	(b) there is a very small current due to minority carriers	
	(c) there is an avalanche current	
3	When forward-biased, a diode	
	(a) blocks current (b) conducts current	
	(c) has a high resistance (d) drops a large voltage	
4	The dynamic resistance can be important when a diode is	
	(a) reverse-biased (b) forward-biased	
	(c) in reverse breakdown (d) unbiased	
5	Ideally, a diode can be represented by a	
	(a) voltage source (b) resistance (c) switch (d) all of these	
6	In the complete diode model,	
	(a) the barrier potential is taken into account	
	(b) the forward dynamic resistance is taken into account	
	(c) the reverse resistance is taken into account	
<u> </u>	(d) all of these	
7	When a 60 Hz sinusoidal voltage is applied to the input of a half-wave	
	rectifier, the output frequency	
	is (a) 120 Hz (b) 20 Hz (a) 60 Hz (d) 0 Hz	
0	(a) 120 Hz (b) 30 Hz (c) 60 Hz (d) 0 Hz For the circuit in Question 15, the diode must be able to withstand a	
8	reverse voltage of	
9	(a) 10 V (b) 5 V (c) 20 V (d) 3.18 V When a 60 Hz sinusoidal voltage is applied to the input of a full-wave	
9	rectifier, the output frequency	
	is	
	(a) 120 Hz (b) 60 Hz (c) 240 Hz (d) 0 Hz	
10	When the peak output voltage is 100 V, the PIV for each diode in a	
10	center-tapped full-wave	
	rectifier is (neglecting the diode drop)	
	(a) 100 V (b) 200 V (c) 141 V (d) 50 V	
L	(4) (4) === . (4) (4) == .	





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Problems 2

Q2	Explain why a series resistor is necessary when a diode is forward-biased.
Sol 2	
Q4	What would cause the barrier potential of a silicon diode to decrease from 0.7 V to 0.6 V?
Sol 4	
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Q6	Determine the voltage across each diode in Figure 2–92, assuming the practical model.
Sol 6	
3010	





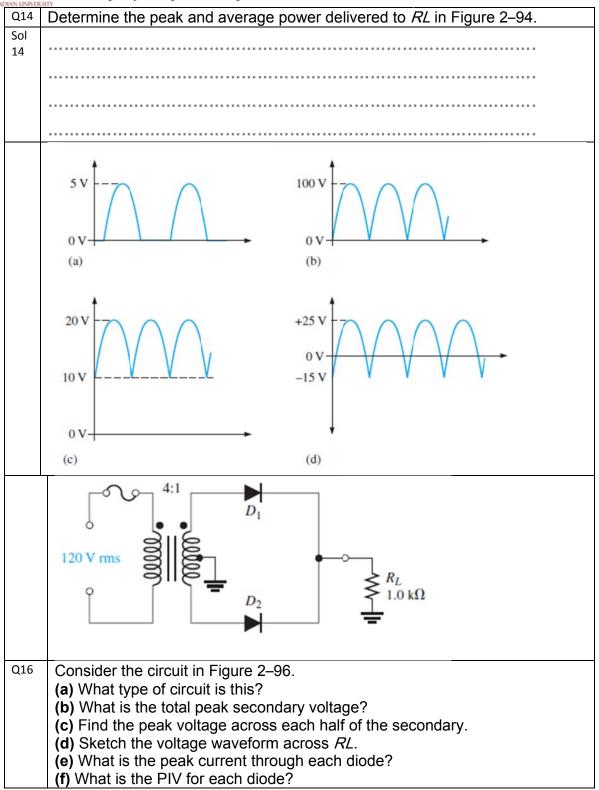
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Q8	Determine the voltage across each diode in Figure 2–92, using the complete
	diode model with
	$r' \cdot d = 10 \text{ A} \text{ and } r' \cdot R = 100 \text{ MA}.$
Sol 8	
	$V_{in} = 0$ -5 V $V_{in} = 0$ -50 V -50 V -50 V -50 V
	(a) (b)
Q10	What is the peak inverse voltage across each diode in Figure 2–93?
Sol 10	
Q12	What is the peak forward current through each diode in Figure 2–93?
Sol 12	
	120 V rms = R _L 2220 Ω





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SERVICE STREET	
Sol	
16	
Q18	Show how to connect the diodes in a center-tapped rectifier in order to produce a negative-going
	full-wave voltage across the load resistor
Sol	
18	